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Substitute for Form 1449/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)		Complete if Known	
		Application Number	10/523,551
		Filing Date	January 31, 2005
		First Named Inventor	Dominik EISERT
		Art Unit	2815
Examiner Name		Joseph Nguyen	
Sheet	1	of	2
		Attorney Docket Number	5367-146PUS

U.S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number Number-Kind-Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US-6,229,160 B1	05/08/2001	Krames et al.	
		US-6,111,272	08/29/2000	Heinen	
		US-6,649,939 B1	11/18/2003	Wirth	
		US-6,445,010 B1	09/03/2002	Ebeling	
		US-5,200,668	04/06/1993	Ohashi et al.	
		US-5,633,527	05/27/1997	Lear	
		US-2003/0141496	07/31/2003	Illek et al.	
		US-2002/0017652	02/14/2002	Illek et al.	
		US-6,730,939 B2	05/04/2004	Eisert et al.	

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Examiner Initials*	Cite No. ¹	Foreign Patent Document Country Code ³ Number ⁴ Kind-Code ⁵ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
		DE 198 07 758 A1	12/10/1998	Krames et al.		
		DE 199 11 717 A1	09/28/2000	Späth et al.		Abstract
		DE 100 20 464 A1	11/08/2001	Härle et al.		Abstract
		DE 199 43 406 C2	07/19/2001	Wirth		Abstract
		JP 8-288543	11/01/1996	Takahashi		Abstract
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		WO 01/61765 A1	08/23/2001	Eisert et al.		Abstract
		WO 02/41406 A1	05/23/2002	Eliashchev et al.		
		WO 96/37000	11/21/1996	Heinen		Abstract
		WO 96/26550	08/29/1996	Fischer et al.		Abstract
		WO 00/60648	10/12/2000	Heinen		Abstract
		WO 90/05998	05/31/1990	Ohashi et al.		Abstract
		WO 99/14797	03/25/1999	Lo		Abstract

Examiner Signature	/Joseph Nguyen/	Date Considered	02/29/2008
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Sheet 2 of 2	Attorney Docket Number	5367-146PUS	

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
	1.	I. Schnitzner et al., "30% External Quantum Efficiency from Surface Textured LEDs", Applied Physics Letters, Oct. 1993, Vol. 63, Pgs. 2174-2176.	
	2.	R. Windisch et al., "High-Efficiency Surface-Textured LEDs", Compound Semiconductor 6 (4) 2000, IMEC, Leuven, Belgium, pp. 55-58	
	3.	J. Cao et al., "Improved quality GaN by growth on compliant silicon-on-insulator substrates using metalorganic chemical vapor deposition", Applied Physics Letters, 83(7) 1998 pgs. 3829-3834 (Univ. of Michigan)	
	4.	A.J. Steckel, "Growth and Characterization of GaN Thin Films on SiC SOI Substrates", Journal of Electron. Mat. 26(3) 1997, pgs. 217-223	
	5.	W.S. Wong, "Integration of GaN Thin Films with Dissimilar Substrate Materials by Pd-In Metal bonding and laser Lift-off", Journal of Electron. Mat. 28(12) 1999, pgs. 1409-1413 (Univ. of California, Berkeley)	
	6.	Y.K. Song, "Resonant-cavity InGaN quantum-well blue light-emitting diodes", Applied Physics Letters 77(12) 2000, pgs. 1744-1746 (Brown University, Agilent)	

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